

Vishay Siliconix

N-Channel 100-V (D-S) MOSFET

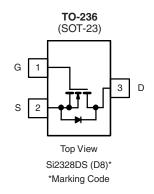
PRODUCT SUMMARY				
V _{DS} (V)	R _{DS(on)} (Ω)	I _D (A)		
100	0.250 at V _{GS} = 10 V	1.5		

FEATURES

- Halogen-free According to IEC 61249-2-21 • Available
- 100 % Rg Tested
- TrenchFET[®] Power MOSFET



COMPLIANT HALOGEN FREE Available



Ordering Information: Si2328DS-T1-E3 (Lead (Pb)-free) Si2328DS-T1-GE3 (Lead (Pb)-free and Halogen-free)

Parameter		Symbol	5 s	Steady State	Unit
Drain-Source Voltage		V _{DS}	100		V
Gate-Source Voltage		V _{GS}	± 20		
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 25 °C	– I _D	1.5	1.15	
	T _A = 70 °C		1.2	0.92	
Pulsed Drain Current ^b		I _{DM}	6		A
Avalanche Current ^b	L = 0.1 mH	I _{AS}	6		
Single Avalanche Energy		E _{AS}	1.8		mJ
Continuous Source Current (Diode Conduction) ^a		۱ _s	0.6		А
Power Dissipation ^a	T _A = 25 °C	PD	1.25	0.73	W
	T _A = 70 °C	' ^{' D}	0.80	0.47	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150		°C

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
	t ≤ 5 s	- R _{thJA} R _{thJF}	80	100	
Maximum Junction-to-Ambient ^a	Steady State		130	170	°C/W
Maximum Junction-to-Foot	Steady State		45	55	

Notes: a. Surface Mounted on 1" x 1" FR4 board. b. Pulse width limited by maximum junction temperature.

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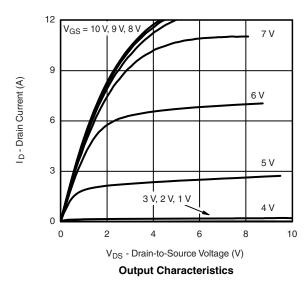


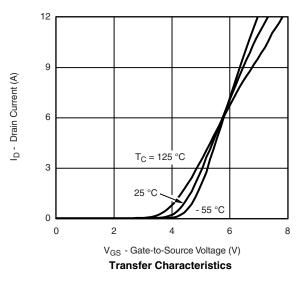
			Limits				
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static							
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0 V, I_{D} = 1 mA$	100			v	
Gate-Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250 \ \mu A$	2		4	v	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 20 V$			± 100	nA	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = 100 V, V _{GS} = 0 V			1		
		V_{DS} = 100 V, V_{GS} = 0 V, T_{J} = 70 °C			75	μΑ	
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge$ 15 V, V_{GS} = 10 V	6			Α	
Drain-Source On-Resistance ^a	R _{DS(on)}	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 1.5 \text{ A}$		0.195	0.250	Ω	
Forward Transconductance ^a	9 _{fs}	$V_{DS} = 15 \text{ V}, \text{ I}_{D} = 1.5 \text{ A}$		4		S	
Diode Forward Voltage	V _{SD}	$I_{S} = 1.0 \text{ A}, V_{GS} = 0 \text{ V}$		0.8	1.2	V	
Dynamic ^b							
Total Gate Charge	Qg			3.3	4.0	nC	
Gate-Source Charge	Q _{gs}	V_{DS} = 50 V, V_{GS} = 10 V, I_D = 1.5 A		0.47			
Gate-Drain Charge	Q _{gd}			1.45			
Gate Resistance	Rg		0.5		2.4	Ω	
Switching							
Turn-On Delay Time	t _{d(on)}			7	11		
Rise Time	t _r	V_{DD} = 50 V, R_L = 33 Ω		11	17	ns	
Turn-Off Delay Time	t _{d(off)}	$\text{I}_{\text{D}}\cong$ 0.2 A, V_{GEN} = 10 V, R_{g} = 6 Ω		9	15		
Fall Time	t _f			10	15		
Source-Drain Reverse Recovery Time	t _{rr}	I _F = 1.5 A, dl/dt = 100 A/μs		50	100		

Notes: a. Pulse test: PW \leq 300 µs, duty cycle \leq 2 %. b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



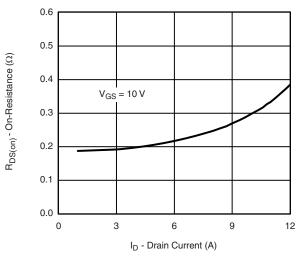




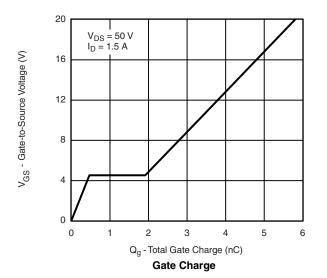
Si2328DS

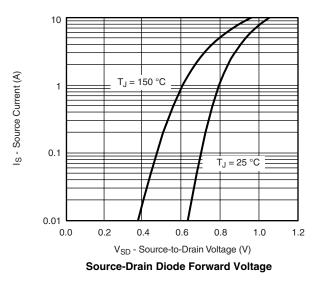
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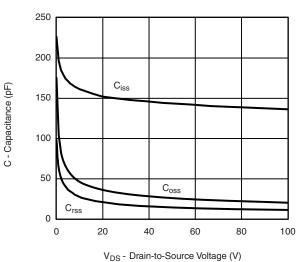
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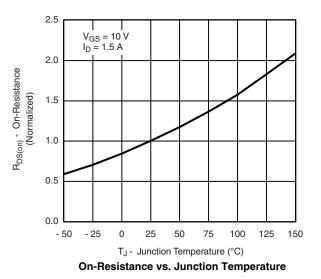
On-Resistance vs. Drain Current

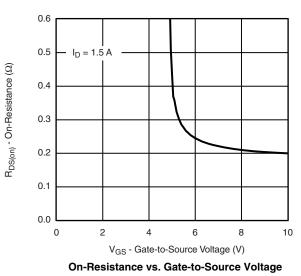






Capacitance





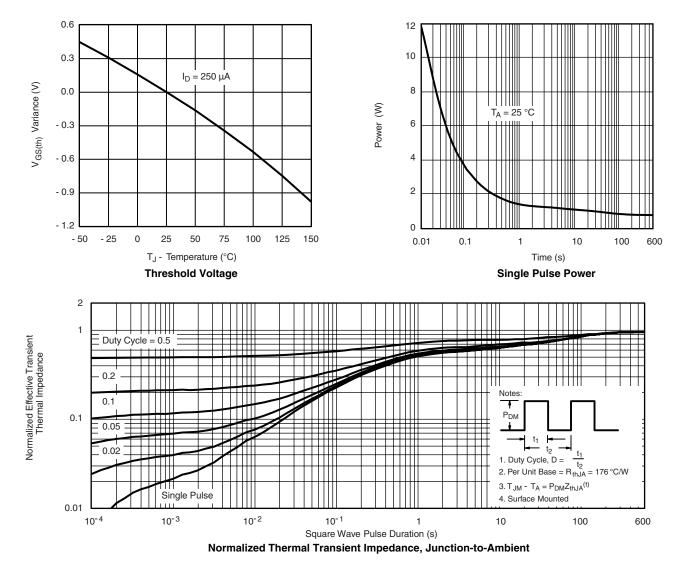
Document Number: 71796 S09-0130-Rev. D, 02-Feb-09

Si2328DS

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Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see <u>www.vishay.com/ppg?71796</u>.

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